Supporting Information

Cs₃Bi₂I₉ Nanodiscs with Phase and Bi (III) State Stability under Reductive Potential or Illumination for H₂ Generation from Diluted Aqueous HI

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Figure S1. Variation of FWHM with 2θ for $Cs_3Bi_2I_9$ NDs.



Figure S2. Additional TEM and HRTEM images of Cs₃Bi₂I₉ NDs.



Figure S3. AFM image, height profile and 3D AFM image of $Cs_3Bi_2I_9$ NDs prepared with reaction times of (a-c) 3 s, (d-f) 15 s, and (g-i) 60 s.



Figure S4. (a) HAADF-STEM mapping showing the elemental distribution. (b) FE-SEM image of agglomerated $Cs_3Bi_2I_9$ ND clusters. (c) EDAX spectrum showing surface elemental stoichiometry of the NDs. (d) Elemental mapping from a selected region shown on the left.



Figure S5. (a) FTIR and (b) Raman spectra of Cs₃Bi₂I₉ NDs.

Raman spectral bands	Assignment
63 cm ⁻¹	bending mode of Bi-I
82 cm ⁻¹	asymmetric stretching of bridged Bi-I
104.5 cm ⁻¹	symmetric stretch of bridging Bi-I
119.8 cm ⁻¹	asymmetric stretching of terminal Bi-I
146.6 cm ⁻¹	symmetric stretching of terminal Bi-I



Figure S6. Absorption spectra of $Cs_3Bi_2I_9$ NDs in 6.34M aqueous HI with different molar concentrations of the NDs (in mol L⁻¹).



Figure S7. (a) Chronoamperometric stability plots of $Cs_3Bi_2I_9$ NDs at -0.5V and -1V versus SCE where 0.66 mg/cm² ND loaded CFP was dipped inside 0.005M ND saturated 0.63M and 6.34M HI solutions. Fitted XPS Bi *4f* level for the NDs in (b) 6.34M HI at -0.5V after 16h, (c) 0.63M HI at -0.5V after 8h, and for the bulk $Cs_3Bi_2I_9$ in (d) 6.34M HI at -1V after 16h, (e) 0.63M HI at -1V after 8h. The open circles are the experimental data, and the solid line represent the best fit. Sat. denotes the satellite peaks. (f) PXRD patterns of the NDs and bulk $Cs_3Bi_2I_9$ after the electrochemical stability tests.



Figure S8. PXRD pattern of Cs₃Bi₂I₉ NDs before and after dispersing in DI water for 12h.



Figure S9. Schematic showing the plausible reason for the $Cs_3Bi_2I_9$ ND stability in 0.63 M saturated HI solution.

Table S1. XPS fitting parameters of $Cs_3Bi_2I_9$ ND and bulk phases after chronoamperometry tests at -0.5 and -1.0 V versus SCE, for 16h in 6.34M HI and 8h in 0.63M HI solution.

Condition	XPS levels	BE (Bi ^{δ+})	Area (Bi ^{δ+})	BE (Bi ³⁺)	Area (Bi ³⁺)	BE (Sat.)	Area (Sat.)	Bi ^{δ+} Wt %	Av. Bi ^{δ+} Wt%	Av. Bi ³⁺ Wt%
Cs ₃ Bi ₂ I ₉ NDs post chronoamperometry										
6.34 M -0.5 V	$4f_{7/2}$	157.1	1155.6	158.9	3211.9	160.0	1059.7	26.5	22	78
	$4f_{5/2}$	162.5	443.2	164.2	1985.4	165.5	518.8	18.2		
6.34 M	$4f_{7/2}$	157.0	2252.7	159.2	4518.0	160.2	819.9	33.2	28	72
-1.0 V	$4f_{5/2}$	162.3	957.5	164.6	3074.0	165.6	934.6	23.7	20	12
0.63 M	$4f_{7/2}$	157.1	47.4	159.1	1401.9	160.8	88.7	3.3	3	97
-0.5 V	$4f_{5/2}$	163.5	19.7	164.4	829.3	165,3	110.9	2.3		
0.63 M -1.0 V	$4f_{7/2}$	157.6	249.4	159.1	1907.1	160.0	172.8	11.5	7	93
	$4f_{5/2}$	163.3	40.5	164.4	1449.2	165.5	146.2	2.7		



Figure S10. (a) Absorption spectrum, (b) PL spectrum, (c) UV photoelectron spectrum with inset showing the band alignment, and (d) valence band XPS spectrum of $Cs_3Bi_2I_9$ NDs.



Figure S11. Solubility plot of $Cs_3Bi_2I_9$ NDs in 6.34M (50%) aqueous HI solution at different temperatures. Error bars indicate standard deviation from three trials.



Figure S12. (a) Photocatalytic H_2 evolution by splitting of aqueous HI solution in the presence (saturation) and absence of $Cs_3Bi_2I_9$ NDs. (b) Photocatalytic H_2 evolution from 6.34M HI solution saturated by 0.005M $Cs_3Bi_2I_9$ NDs under dark condition and in the presence of visible light illumination.



Figure S13. (a) Absorption spectra showing the temporal emergence of I_3^- ions. (b) Time dependent increase of I_3^- concentration, measured using the absorbance band at 350 nm. (c) Absorption spectra showing the absence of I_3^- ions during the photocatalytic reaction in 6.34M HBr solution saturated by 0.005M Cs₃Bi₂I₉ NDs.

Discussion S1. Quantum yield calculation

The quantum efficiency of HI splitting was estimated by calculating the apparent quantum efficiency (AQE) according to equation (S1):

$$AQE = \frac{Evolved H_2(mol) \times 6.02 \times 10^{23} \times 2 \times 0.33(eV) \times 1.6 \times 10^{-19}}{P_{sol}(Wcm^{-2}) \times Area(cm^2) \times time(s)} \times (S1)$$

The evolved gas by photocatalytic HI splitting = $11.3 \mu mol h^{-1}$;

Avogadro Number = 6.022×10^{23} ;

 P_{sol} is the power density of the incident monochromatic light = 450 W lamp calibrated to 150 mWcm⁻²; Area = Irradiated area to produce (mol) of hydrogen = 0.2 cm²;

Irradiated time = 1 h = 3600 s; Electronic charge = 1.6×10^{-19} C

Since H^+/H_2 reduction potential is 0.046V versus NHE and I^-/I_3^- oxidation potential is 0.376V versus NHE, the total potential for HI splitting is 0.376 V – 0.046 V = 0.33 V.

Hence, AQE is calculated as 0.66 % ~ 0.7%. With H_3PO_2 and Pt co-catalyst, 22.5µmol h⁻¹ H_2 is equivalent to a quantum efficiency of 1.3%.

Table S2. Comparative list of the photocatalytic HI splitting activity by pristine and composite metal-halide perovskites with respect to $Cs_3Bi_2I_9$ NDs.

Photocatalysts	Light source	Reaction	H ₂ activity	Ref.
	(λ in nm)	medium		
Cs ₃ Bi ₂ I ₉ NDs	150 mW cm ⁻²	Saturated	11.3 μmol h ⁻¹	This
	Xe lamp ($\lambda \ge 420$ nm)	HI		work
Cs ₃ Bi ₂ I ₉ NDs /Pt	150 mW cm ⁻²	Saturated	22.5 μmol h ⁻¹	This
	Xe lamp ($\lambda \ge 420$ nm)	HI		work
MAPbI ₃	300 W Xe lamp	Saturated	30.0 µmol h ⁻¹ g ⁻¹	S1
	$(\lambda > 475 \text{ nm})$	HI		
MAPbI ₃ /Pt	100 W solar simulator	Saturated	57 μmol h ⁻¹ g ⁻¹	S1
	$(\lambda > 475 \text{ nm})$	HI		
MAPbBr _{3-x} I _x /Pt	300 W Xe lamp	Saturated	651.2 μmol h ⁻¹	S2
	$(\lambda \ge 420 \text{ nm})^{-1}$	HI/HBr		
CsPbBr _{3-x} I _x /Pt	300 W Xe lamp	Saturated	224 μmol h ⁻¹	S3
	$(\lambda \ge 420 \text{ nm})^{-1}$	HI/HBr		
MAPbI ₃ /Pt/TiO ₂	300 W Xe lamp	Saturated	29 µmol h-1	S4
	$(\lambda > 420 \text{ nm})$	HI		
MAPbI ₃ /rGO	300 W Xe lamp	Saturated	93.9 μmol h ⁻¹	S5
	$(\lambda \ge 420 \text{ nm})$	HI		
$MAPb(I_{0.9}Br_{0.1})_3$	300 W Xe lamp	Saturated	1471 μmol h ⁻¹ g ⁻¹	S6
	$(\lambda \ge 420 \text{ nm})$	HI/HBr		
Ni ₃ C/MAPbI ₃	300 W Xe lamp	Saturated	2362 µmol h ⁻¹ g ⁻¹	S7
	$(\lambda \ge 420 \text{ nm})$	HI		
MA ₃ Bi ₂ I ₉ /Pt	300 W	Saturated	169 µmol h ⁻¹	S8
	$(\lambda \ge 400 \text{ nm})$	HI		
MAPbI ₃ /	100 mW cm-2	Saturated	23.30 µmol h ⁻¹	S9
(piezoelectric)	$(\lambda \ge 420 \text{ nm})$	HI		
$[(CH_3)_2NH_2]_3[BiI_6]$	465 nm LED	Saturated		S10
(PtI _x)		HI		
MA ₃ Bi ₂ I ₉ /	300 W Xe lamp	Saturated	198.2 µmol h ⁻¹ g ⁻¹	S11
DMA ₃ BiI ₆	$(\lambda \ge 420 \text{ nm})$	HI		
MAPbI ₃ /cobalt	150 W Xe lamp ($\lambda \ge$	Saturated	785.9 μmol h ⁻¹ g ⁻¹	S12
phosphide	420 nm)	HI		
$Cs_3Bi_{0.6}Sb_{1.4}I_9$	100 W solar simulator	Saturated	92.6 µmol h ⁻¹	S13
		HI		



Figure S14. Recyclability test of the NDs for three 5h runs in 0.63M aqueous HI.



Figure S15. Additional TEM images of $Cs_3Bi_2I_9$ NDs after 10h photocatalysis in 0.005 M ND saturated (a-c) 6.34 M and (d-f) 0.63 M aqueous HI solutions.



Figure S16. Absorption spectra of Cs₃Bi₂I₉ NDs before and after 10h photocatalysis.



Figure S17. XPS spectra of $Cs_3Bi_2I_9$ NDs (a, b) before and (c, d) after photocatalysis. The C *Is* binding energy of 284.8 eV was used as reference.



Figure S18. (a) Digital images of the H-cell containing ND saturated aqueous HI solution (i) before, and after electrochemical reduction for (ii) 1h, (iii) 2h, and (iv) 3h. A proton exchange membrane (Nafion) between left and the right slots of the H-cell, allows the solution color to change exclusively in the right slot from dark brown to light yellowish orange due to the continuous electrochemical reduction of I_3^- to I^- over time.

Discussion S2: TOF calculation

The number of hydrogen turnover is calculated from the current density according to:

turnover

=

Number of hydrogen

$$\left(j\frac{mA}{cm^2}\right)\left(\frac{1 C/s}{1000 mA}\right)\left(\frac{1 mol e}{96485.3 C}\right)\left(\frac{1 mol H_2}{2 mol e}\right) \times (6.023 \times 10^{23})$$

For 6.34M HI Saturated Cs3Bi2I9 NDs

Specific capacitance (C_s) = 0.04 mF/cm² Double layer capacitance (C_{dl}) = 2.4 mF

$$ECSA = \frac{Cdl}{Cs} = \frac{2.4}{0.04} = 60 \text{ cm}^2$$

At 533 mV overpotential, Cs₃Bi₂I₉ NDs reach a current density of -100 mAcm⁻².

Number of hydrogen turnover for Cs₃Bi₂I₉ NDs at 533 mV overpotential:

$$\left(100\frac{mA}{cm^2}\right)\left(\frac{1\ C/s}{1000\ mA}\right)\left(\frac{1\ mol\ e}{96485.3\ C}\right)\left(\frac{1\ mol\ H_2}{2\ mol\ e}\right)\times\ (6.023\times\ 10^{23})=3.1212\times10^{17}\left(\frac{1/s}{cm^2}\right)$$

Based on ECSA along with the unit cell volume (1295.66 Å³) of $Cs_3Bi_2I_9$ NDs, active sites per real surface area:

Active Surface sites =
$$\left(\frac{2 \text{ atom/unit cell}}{1293.96 \text{ Å}^3/\text{unit cell}}\right)^{2/3} = 0.0133 \times 10^{16} \text{atoms } \text{cm}^{-2}_{\text{real}}$$

 $3.122 \text{ x } 10^{17} \left(\frac{1/s}{\text{cm}^2}\right) \times 0.3 \text{ cm}^2$

TOF
$$(\eta_{533}) = \overline{Active Surface sites \times ECSA} = 11.736 \text{ s}^{-1}$$

Therefore, TOF of Cs₃Bi₂I₉ NDs for HER is 11.7 s⁻¹ at an overpotential of 533 mV.



Figure S19. ECSA determination of $Cs_3Bi_2I_9$ ND electrocatalyst. (a) CV cycles at different scan rates. (b) Current density as function of scan rate at fixed overpotential.



Figure S20. LSV polarization curves showing the electrochemical HER activity of Cs₃Bi₂I₉ NDs, MAPbI₃ and FAPbI₃ [MA: CH₃NH₃, FA: HC(NH₂)₂].



Figure S21. (a) LSV polarization plots in different electrolyte and catalyst combinations. (b) Comparison of electrochemical HI splitting activity of $Cs_3Bi_2I_9$ NDs with CsI and BiI₃.



Figure S22. Comparison of the electrocatalytic HER activity between the NDs and bulk $Cs_3Bi_2I_9$ in 6.34M HI. (a) LSV polarization plots, (b) Nyquist plots measured at 700 mV overpotential (*iR* uncorrected), and (c) Tafel plots with the corresponding Tafel slopes.



Figure S23. (a) Tafel plots and their corresponding Tafel slopes. (b) Nyquist plots measured at 700 mV overpotential (*iR* uncorrected) for HER. Inset shows the equivalent circuit (R_s : solution resistance; CPE: constant phase element; R_{CT} : charge transfer resistance). (c) Faradaic efficiency measured at 1V overpotential (*iR* uncorrected) showing the theoretically calculated and experimentally measured H₂ gas with time. Inset shows digital image of the measurement setup. The samples: (1) 12.69 M HI, (2) 6.34 M HI, (3) 3.17 M HI, (4) 1.26 M HI, and (5) 0.63 M HI.

Supporting References

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